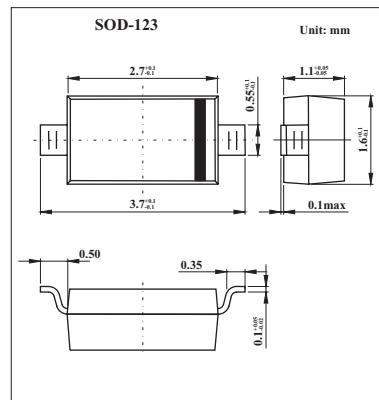


## SURFACE MOUNT SCHOTTKY BARRIER DIODE

### BAT42W/BAT43W

#### ■ Features

- Low Forward Voltage Drop
- Fast Switching Time
- Surface Mount Package Ideally Suited for Automatic Insertion



#### ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	30	V
Working Peak Reverse Voltage	V <sub>RWM</sub>	30	V
DC Blocking Voltage	V <sub>R</sub>	30	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	21	V
Forward Continuous Current (Note 1)	I <sub>FM</sub>	500	mA
Repetitive Peak Forward Current (Note 1) @ t < 1.0s	I <sub>FRM</sub>	200	mA
Non-Repetitive Peak Forward Surge Current @ t < 10ms	I <sub>FSM</sub>	4	A
Power Dissipation	P <sub>d</sub>	200	mW
Thermal Resistance Junction to Ambient Air (Note 1)	R <sub>θJA</sub>	500	°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to + 150	°C

Note 1

1. Part mounted on FR-4 board with recommended pad layout

## SURFACE MOUNT SCHOTTKY BARRIER DIODE

### BAT42W/BAT43W

#### ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Conditions	Min	Max	Unit
Reverse Breakdown Voltage (Note 2)	V <sub>R</sub>	I <sub>R</sub> = 100 μ A	30		V
Forward Voltage Drop (Note 2) BAT42W	V <sub>RM</sub>	I <sub>F</sub> = 10 mA		0.4	V
		I <sub>F</sub> = 50 mA		0.65	
Forward Voltage Drop (Note 2) BAT43W	V <sub>RM</sub>	I <sub>F</sub> = 2.0 mA	0.26	0.33	V
		I <sub>F</sub> = 15 mA		0.45	
Peak Reverse Current (Note 2)	I <sub>RM</sub>	V <sub>R</sub> = 25V V <sub>R</sub> = 25 V, T <sub>j</sub> = 100°C		500 100	nA μ A
Total Capacitance	C <sub>T</sub>	V <sub>R</sub> = 1.0 V, f = 1.0MHz		10	pF
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = I <sub>R</sub> = 10 mA, I <sub>rr</sub> = 0.1 x I <sub>R</sub> , R <sub>L</sub> = 100 Ω		5.0	ns
Rectification Efficiency	η <sub>V</sub>	R <sub>L</sub> = 15 Ω , C <sub>L</sub> = 300pF, f = 45MHz, V <sub>RF</sub> = 2.0V	80		%

Note

2.Short duration pulse test used to minimize self-heating effect.

#### ■ Marking

Type	BAT42W	BAT43W
Marking	S7	S8